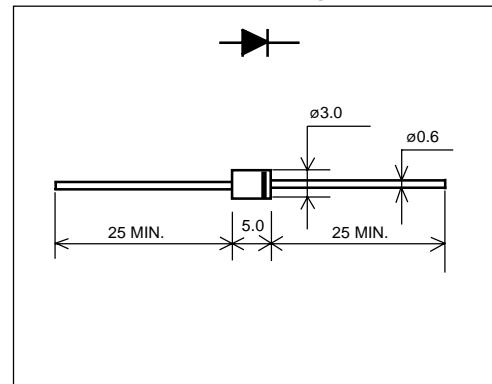


SCHOTTKY BARRIER DIODE

■ Outline drawings, mm



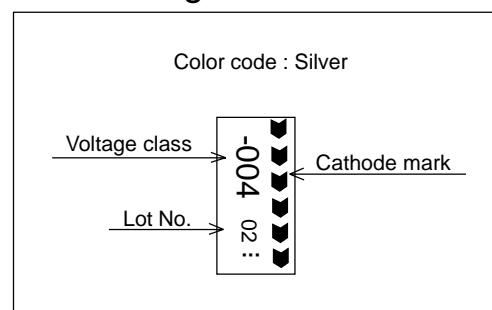
■ Features

- Low VF
- Super high speed switching
- High reliability by planer design

■ Applications

- High speed switching

■ Marking



■ Maximum ratings and characteristics

- Absolute maximum ratings

Item	Symbol	Conditions	Rating	Unit
Repetitive peak reverse voltage	V _{RRM}		40	V
Average forward current	I _{F(AV)}	Sine wave duty = 1/2 Ta=25°C	1.0	A
Surge current	I _{FSM}	Sine wave 10ms	50	A
Operating junction temperature	T _j		-40 to +150	°C
Storage temperature	T _{stg}		-40 to +150	°C

- Electrical characteristics (Ta=25°C Unless otherwise specified)

Item	Symbol	Conditions	Max.	Unit
Forward voltage drop	V _{FM}	I _{FM} =1.0A	0.55	V
Reverse current	I _{RRM}	V _R =V _{RRM}	2.0	mA

■ Characteristics

